5.

By Eq. (5.7), doubling IA will double gms, thus increasing the open-loop fain a. This will also double the input bias currents Ip & In, and halve the input resistance of and the first-stage output resistance for. The reduction in for will affect loading of the first stage by the second stage, thus affecting a. Furthermore, the first-stage output-aussent saturation levels will also double; in Ch. 6 we'll see that this doubles the slew rate.

[5.2]  $R_2 = 10R_1$ . With  $R_p = R_1//R_2 = 0.91R_1$  in place,  $E_0(mex) = (1+R_2/R_1)(R_1//R_2) I_{05}(mex) = 11 \times 0.91R_1 \times 200 \times 10^{-9} = 10 \times 10^{-3}$ . This yields  $R_1 = 5 \text{ k. R.}$ . Use  $R_1 = 4.99 \text{ k. R.}$ ,  $R_2 = 49.9 \text{ k. R.}$ , and  $R_p = 45.3 \text{ k. R.}$ , all 1%.

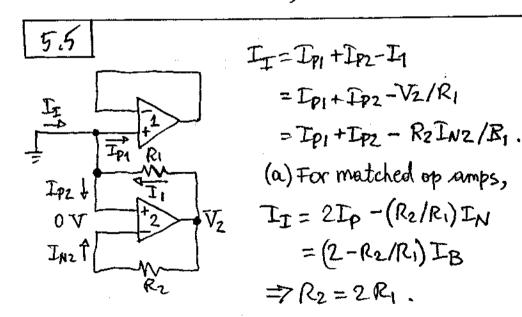
[5.3] (a) Suppress  $\frac{1}{2}$  and find Eo.  $RIB = 10^5 \times 10^{-8} = \frac{1}{2}$  ROV R  $\frac{1}{2}$  mV  $\frac{1}{2}$   $\frac{1}{2}$  mV  $\frac{1}{2}$   $\frac{$ 

(b) We readily find the moise gain to be 1/B= 13 V/V. We thus need RpIB= (8 mV)/13 => Rp=61.5 kr (Use 62 kr).

(5.2)

 $V_N = V_P$ ;  $\frac{P_0 - V_N}{20 \text{ k }\Omega} = I_N + \frac{V_N}{50 \text{ k}\Omega}$ ;  $\frac{P_0 - V_P}{40 \text{ k}\Omega} = I_P + \frac{V_P}{10 \text{ k}\Omega}$  $\Rightarrow P_0 = \frac{250 \times 10^3 \text{ In} - 140 \times 10^3 \text{ I}_P}{9}$ 

With Ip=105 mA and In=95 mA we get Eo=1.005 mV; with Ip=95 mA and IN =105 mA we get Eo=1.438 mV. We thus expect to within the range of 1.005 mV to 1.438 mV. With Ios=0, Eo=1.2 mV.

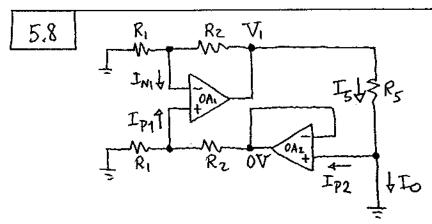


(b) Assume  $I_{P1}=I_B$ ,  $I_{P2}=I_{W2}=I_B(1\pm0.01)$ . Then  $I_{I}=I_B+I_B(1\pm0.01)-2I_B(1\pm0.01)=\mp0.01I_B$ , indicating an input current on the order of the mismatch itself. (5.3)

$$\frac{v_0-v_N}{R^2} = I_N + \frac{v_N}{R_1}$$
 $\frac{v_0-v_P}{R^2} = I_P + i_C + \frac{v_P}{R_1}$ 
 $v_N = v_P$ . Combining,
 $i_C = I_N - I_P = -I_{OS}$ 
regardless of the resistance ralues. Consequently,

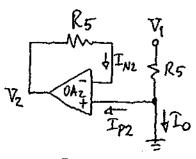






The presence of the bras and offset currents does not affect the resistances, so we expect io =  $A(\nabla_2 - \nabla_1) - \nabla_L/R_0 + I_0$ ,  $A = R_2/R_1R_5$ ,  $R_0 = \infty$ . To find the error  $I_0$ , consider the case of a short-circuit load for simplicity. Then,  $V_1 = R_2 I_{N1} + (I + R_2/R_1)[-(R_1//R_2)I_{P1}] = -R_2 I_{OSI}$ .  $I_0 = I_5 - I_{P2} = V_1/R_5 - I_{P2} = -(R_2/R_5)I_{OSI} - I_{P2}$ . Writing  $I_0 = A \times [-(R_1 I_{OSI} + R_1 I_{P2} R_5/R_2)]$  indicates the presence of an equivalent input voltage error  $E_I = -R_1[I_{OSI} + (R_5/R_2)I_{B2}]$ .

To make the second term proportional to



Tosz rather than IBZ, in-Stall a dummy feedback resistance R5, as shown. Then, V1=-R2 Ios1 + R5 INZ

$$\begin{split} & I_0 = \frac{-R_z I_{OS1} + R_S I_{N2}}{R_5} - I_{P2} = -\frac{R_2}{R_5} I_{OS1} - I_{OS2} \\ & E_I = -R_1 \left[ I_{OS1} + (R_z/R_5) I_{OS2} \right]. \end{split}$$

(5.4)

[5.9] Since  $I_B$  and  $I_{OS}$  do not affect the re-Sistances, we expect io =  $Ai_I - V_L/R_0 + I_O$ ,  $A = 1+R_2/R_1$ ,  $R_0 = 00$ . To find  $I_O$ , consider a shortcircuited load for simplicity.

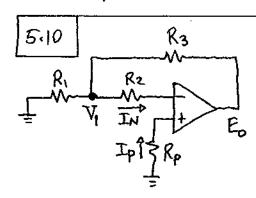
$$\frac{O-V_0}{R_1} = I_N + I_O \Rightarrow I_O = -\left(\frac{V_0}{R_1} + I_N\right)$$

$$V_0 = V_N + R_2 I_N = V_P + R_2 I_N =$$

$$-R_P I_P + R_2 I_N.$$

Eliminating Vo fives

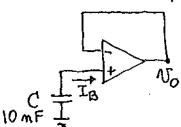
 $T_0 = \frac{R_P}{R_1} I_P - (1 + \frac{R^2}{R_1}) I_N$ . With  $R_P = 0$  we get  $I_0 \cong$   $-(1 + R^2/R_1) I_B$ , indicating an equivalent input word  $I_I = -I_B$ . Installing a dummy resistance  $R_P = R_1 + R_2$  gives  $I_0 = (1 + R_2/R_1) I_{OS}$ , for an equivalent input even  $I_I = I_{OS}$ .



At dc caps = open ckts.  $\frac{E_0 - V_1}{R_3} + \frac{0 - V_1}{R_1} = I_N \Rightarrow$   $E_0 = \left(1 + \frac{R_3}{R_1}\right) V_1 + R_3 I_N$   $V_1 = R_2 I_N + V_N = R_2 I_N - R_P I_P$ 

Eliminating  $V_1$ ,  $E_0 = \left(1 + \frac{R_3}{R_1}\right) \left[ \left(R_2 + R_1 | | R_3\right) I_N - R_P I_P \right]$ . Without  $R_P$ ,  $E_0 = \left(1 + R_3 / R_1\right) \left(R_2 + R_1 | | R_3\right) I_B = 2 \times 150 \times 10^3 \times 50 \times 10^9 = 15 \text{ mV}$ . Installing a dummy vestimate  $R_P = R_2 + R_1 | | R_3 = 150 \text{ hD}$  gives  $E_0 = -\left(1 + \frac{R_3}{R_1}\right) \left(R_2 + R_1 | | R_3\right) I_{05} = -300 \times 10^3 I_{05}$ .

(5.6)

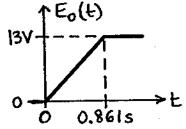


(a) 
$$I_8 = C |dv_0/dt| = 10^{-8} \times 10^{-3}/1 = 10$$

PA > FET-input op amp.

(b) To increase IB by a factor of 100 we need

$$100 = 2^{\Delta T/10} \Rightarrow \Delta T = 66.4 °C.$$

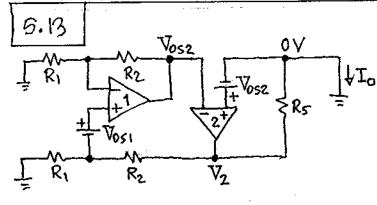


1.51 mV.

$$E_o(t) = \frac{1}{Rc} V_{os} t =$$

$$\frac{1}{10^5 \times 10^{-9}} \times 1.51 \times 10^{-3} t = 15.1t$$

The output saturates at t=13/15.1=0.861s.

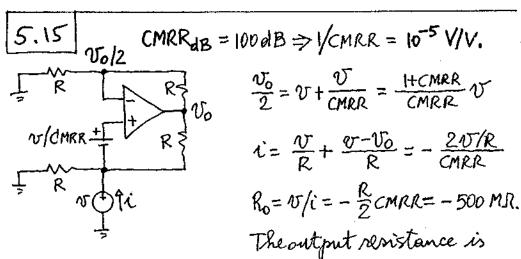


The presence of Vosi and Vosz does not affect the resistances of

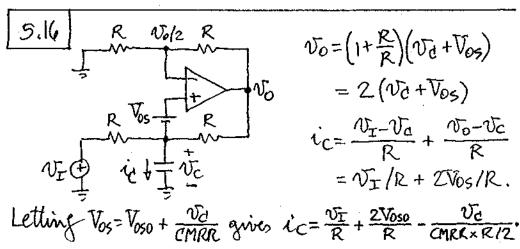
the circuit, so we expect  $i_0 = AV_I - V_L/R_0 + I_0$ ,  $A = R_2/R_1R_5$ ,  $R_0 = \infty$ . To find  $I_0$ , consider a short-circuit load for simplicity.  $I_0 = V_2/R_5$ ; moreover,  $V_{N1} = \left[R_1/(R_1+R_2)\right]V_{052} = V_{P1} = \left[R_1/(R_1+R_2)\right]V_2 + V_{051}$ . This gives  $I_0 = \left(\frac{1}{R_5}\right)\left[V_{052} - \left(1 + \frac{R^2}{R_1}\right)V_{051}\right]$ , indicating an equivalent input error  $I_T = \frac{R_1R_5}{R_2}I_0 = \frac{R_1}{R_2}V_{052}$   $\left(1 + \frac{R_1}{R_2}\right)V_{051}$ .

5.14 (a)  $E_0 = (1+10^5110) V_{05} = 10^4 V_{05}; |E_0(000)|^{\frac{1}{2}}$  $10^4 (5 \times 10^6 \times 25) = 1.25 \text{ V}; |E_0(2500)| \approx 10^4 (5 \times 10^{-6}) \times (70-25) = 2.25 \text{ V}; opposite polarities.}$ 

(b)  $V_0(t) = \pm (V_{0s}/RC)t + V_0(0) = \pm [5 \times 10^{-6} \times 25/(10^5 \times 10^{-9})]t + V_0(0) = \pm 1.25t + V_0(0); V_0(t) = \pm 2.25t + V_0(0).$ 



negative (or positive), depending on whethe Vos moreases (or decreases) with  $v_{\rm CM}$ .



For  $\nabla_{\Sigma}=0$ , c' sees the Norton equivalent:

Voso ((R/2) = 2 mA |Ro| = 5 G.R. (5.8)

Assuming C is initially discharged, we have two cases:

1. Vos decreases with  $V_{CM}$ ; then  $R_0=+5$  G.I,  $\tau$  =  $R_0C=+5$ s,  $V_{CI}(\infty)=10$  V;  $V_{CI}(t)=10(1-e^{-t/5})$  V;  $V_0=2(V_C+V_{OS})$ . These expressions hold only as long as the open amp is within the linear region.

2. Vos micreases with  $V_{CM}$ ; then  $R_o = -5G_{5}R$ ,  $\mathcal{C} = -5S$ ,  $V_{C}(t) = 10 \left(e^{+t/5} - 1\right) V$ ,  $V_o = 2 \left(V_C + V_{OS}\right)$ .

$$\Delta V_{cm(DA)} = R_2/R_1$$

$$\Delta V_{cm(DA)} = R_2/R_1$$

$$\Delta V_{cm(DA)} = \frac{R_2}{R_1 + R_2} \Delta V_{cm(DA)}$$

$$\Delta V_{os} = \frac{\Delta V_{cm(DA)}}{CMRR_{OA}}$$

 $\Delta V_0 = \left(1 + \frac{\Omega z}{R_1}\right) \Delta V_{0S} = \left(1 + \frac{Rz}{R_1}\right) \frac{\Omega z}{R_1 + Rz} \frac{\Delta V_{CM}(DA)}{CMRR_{0A}}$   $A_{CM} = \frac{\Delta V_0}{\Delta V_{CM}(DA)} = \frac{Rz}{R_1} \frac{1}{CMRR_{0A}} = Adm \frac{1}{CMRR_{0A}}$   $CMRR_{DA} \triangleq Adm/A_{CM} = CMRR_{0A}.$ 

5.18 (a) CMRR DA(min) = CMRROA(min) = 70 dB.

(b) Applying  $\Delta V_{CM}(DA) = 1 \text{ V yields}$   $|\Delta V_{O1}|_{max} = A_{dm} \frac{1 \text{ V}}{CMRROA(min)} = \frac{100 \times 1}{10^{70/20}} = 31.6 \text{ mV}$ due to the op amp finite CMRR. Moreover, by

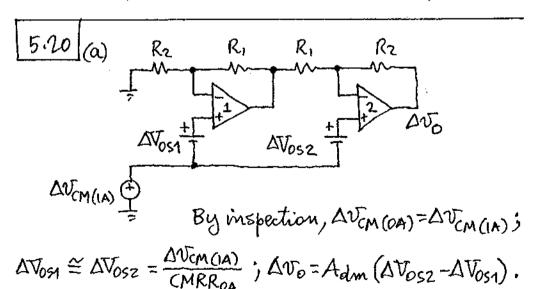
Eq. (2.24c), bridge imbalance yields  $|\Delta V_{O2}|_{max} = \frac{R_2}{R_1 + R_2} |E|_{max} \times (1 \text{ V}) = \frac{100}{1 + 100} 0.04 \times 1 = 39.6 \text{ mV}$ . The worst-case scenario occurs when

5,9

the ontput terms are maximized and convline additively to give  $|\Delta V_0|_{max} = 31.6 + 39.6 = 71.2 \text{ mV}$ .

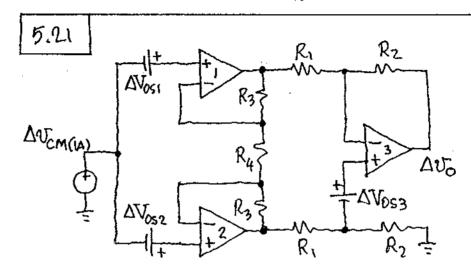
Then,  $|A_{cm}|_{max} = |\Delta V_0|_{max}/\Delta V_{cm(DA)} = 0.0712/1 = 0.0712 \text{ V/V}$ , and  $CMRR_{met}(max) = 20 \log_{10} \frac{100}{0.0712} = 63 \text{ dB}$ . In the present circuit, a 1% resistance tolerance can degrade the CMRR due to the basic op amp by as much as 7 dB.

[5.19] Assuming perfectly matched resistances, we have, by Prob. 5.17, CMRRDA=CMRRD4=90 dB at 1Hz, 76 dB at 1 kHz, and 66 dB at 10 kHz. The corresponding peak variations of Vos are, respectively,  $(1 \text{ V})/10^{90/20} = 31.6 \,\mu\text{V}$ ,  $158 \,\mu\text{V}$ , and 501  $\,\mu\text{V}$ . Multiphyring by the moise gain, which is 101 V/V, gives respectively,  $v_0 \cong 3.2 \times 3.2 \times 3.10 \,\mu\text{V}$ ,  $v_0 \approx 3.10 \,\mu\text{V}$ .



The worst-case scenario occurs when the two terms combine additively to five

 $|\Delta v_0|_{max} = A_{dm} \times 2|\Delta V_{os}|_{max} = 2A_{dm} \Delta v_{cm(1A)}|_{cmRR_{OA(min)}} \Rightarrow$   $A_{cm(max)} = |\Delta v_0|_{max}/\Delta v_{cm(1A)} = 2A_{dm}|_{cmRR_{OA(min)}} \Rightarrow$   $CMRR_{IA(min)} \triangleq \frac{A_{olm}}{A_{cm(max)}} = \frac{1}{2}CMRR_{OA(min)}.$ (b)  $\Delta v_0(max) = 100 \times 2 \times \frac{10 \text{ V}}{10^{114/20}} \approx 4 \text{ mV}.$ 



CMRRIA = Adm ; Adm = AIXAII = (1+ 2R3) × (RZ).

By inspection,  $\Delta V_{CM(0A)} = \Delta V_{CM(0A_2)} = \Delta V_{CM(II)} = \Delta V_{CM(IA)}$ . By Problem 5.17, CMRR<sub>II</sub> = CMRR<sub>0A3</sub>, so the contribution of OA3 to the output is

DVO(II) = Acm (II) DVCM (II) = AIL DVCM(IA) / CMRROA3.

The first-stage contribution to the output is

 $\Delta V_{O(\pm)} = A_{I} A_{II} \left( \Delta V_{OS2} - \Delta V_{OS1} \right)$ 

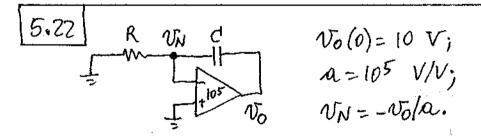
=AIAII (AV<sub>CM(IA)</sub>/CMRR<sub>OA,</sub> - AV<sub>CM(IA)</sub>/CMRR<sub>OAE</sub>). The worst-case scenario occurs when the contributions are maximized and combine additively;

Avolmer = LAVO(I) max + LAVO(II) max

= DVCM (IA) [AIAII (CMRROAI(min) + CMRROAZ(min))

$$\frac{A_{cm (max)} = |\Delta V_0|_{max}/\Delta V_{cm (1A)} = A_{dm} \times [...]}{\frac{1}{CMRR_{1A (min)}} = \frac{A_{cm Cmax}}{A_{dm}} = \frac{1}{CMRR_{0A_1 (min)}} + \frac{1}{CMRR_{0A_2 (min)}} + \frac{1}{(1+2R_3/R_4)CMRR_{0A_2 (min)}}$$

For matched op samps this simplifies to CMRRIA(min) = CMRROA(min) / [2+ 1/1+2R3/R4]. For a sufficiently high first-stage gain, the second-stage CMRR limitation can be ignored compared to the first stage's.



 $(V-V_N)/R = Cd(V_N-V_O)/dt$ . Eliminating  $V_N$  and collecting gives  $V_O(t) = -CdV_O(t)/dt$ , where  $C = (1+\alpha)RC \cong 10^5 \times 10^5 \times 10^{-8} = 100 \text{ s}$ . The solution is  $V_O(t) = 10 e^{-t/(100 \text{ s})} V$ , which represents an exponential decay with a 100 - s time constant.

(5.17)

$$V_0 = \alpha \left( v_I + V_{0s} - V_0 \right) \Rightarrow$$

$$V_0 = \frac{\alpha}{1+\alpha} \left( v_L + V_{0s} \right)$$

$$V_0 - v_I \cong V_{0s} - v_I / \alpha$$

Ideally,  $v_0 = v_{\rm I}$ ; max departure of  $v_0$  from  $v_{\rm I}$  is thus  $\Delta v_0$  (max) = -[ $|v_0|$  max +  $|v_{\rm I}|/a$ ].

(a)  $N_I = 0 \Rightarrow \Delta V_0(max) = -V_{050} = -3 \text{ mV}$ .

(b)  $V_{I} = 10 \text{ V} \Rightarrow \Delta V_{O}(\text{max}) = -(V_{OSO} + 10/104 + 10/1074/20) = -(3+1+2) \text{ mV} = -5 \text{ mV}.$ 

(c)  $\Delta V_S = 3V \Rightarrow \Delta V_{OS} = 3/10^{74/20} = 0.6 \text{ mV}$ . Thus, in (a) we have  $\Delta V_O(\text{mex}) = -3.6 \text{ mV}$ , and in (b) we have  $\Delta V_O(\text{mex}) = -5.6 \text{ mV}$ .

[5.24 (a) By Eq. (5.32), a 10% mismatch between AEI and AEZ yields a 10% mismatch match between Is1 and Is2. By Eq. (5.30), this gives DVos = VT h 1.01 = 0.01×26 mV = 0.26 mV.

(b) A well known rule of thumb states that the voltage drop across a pn junction varies by about 2 mV/el. We thus anticipate that a 1°C gradient across Q, and Qz will yield  $\Delta V_{05} \cong 2 \text{ mV}$ .

(5.13)

5.25 Use  $R_p = R = 100 \text{ k}\Omega$ . Then,  $E_{I}(max) = 6$  mV+100×10<sup>3</sup> × 200×10<sup>9</sup> = 26 mV. Dayrore -30 mV  $\leq V_X \leq 30 \text{ mV}$  for safety. Use  $R_c = 100 \text{ k}\Omega$ ,  $R_B = 100 \text{ k}\Omega$ ,  $R_A = 200 \Omega$ .

 $\begin{array}{c|c} \hline 5.26 & R_1 = R_2 = 0 \Rightarrow E_0 = (1+10^4/10) \ V_{OS} = \\ \hline 1000 \ V_{OS} \Rightarrow V_{OS} = 0.48 \ mV. \ R_1 = 1 \ M.C. \ and \\ \hline R_2 = 0 \Rightarrow E_0 = 1000 \ (V_{OS} + R_1 I_N). \ Thus, \\ \hline I_N = (0.230/1000 - 0.48 \times 10^{-3})/10^6 = -0.25 \\ \hline mA, indicating that I_N flows out of the opening. R_1 = 0 and R_2 = 1 M.C. \Rightarrow E_0 = 1000 \\ \hline \times (V_{OS} - R_2 I_P) \Rightarrow I_P = -(0.780/1000 - 0.48 \times 10^{-3})/10^6 = -0.3 \ mA, flowing out of the opening. Thus, I_B = -(0.25 + 0.3)/2 \\ \hline = 0.275 \ mA, out of opening; I_{OS} = -50 \ pA. \end{array}$ 

[5.27] At dc, the output vo of DUT is such that  $(v_0-0)/10^5 = (0-v_1)/10^5$ , or  $v_0 = -v_1$ . The inputs are, respectively,  $v_N = -R_m I_N$  and  $v_p = [100/(100+49,900)] v_2 - RpIp, where <math>R_m$  and  $R_p$  are the dc resistances presented at DUT's inputs. Imports. Imports  $v_N = v_p + v_{oso} - v_o/a$  gives  $v_2 = 500 \left[ R_p I_p - R_m I_N - v_{oso} - \frac{v_1}{\alpha} \right] Eq.(1)$ 

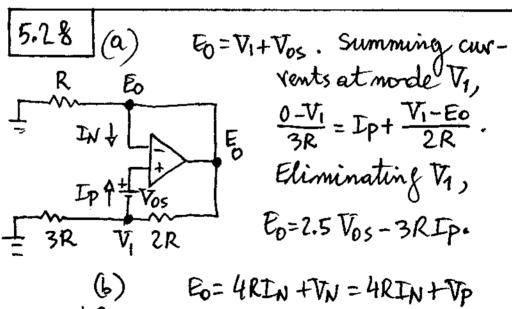
(a) With SW1=SW2= closed we have Rp=

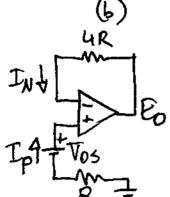
 $R_n = 100 \Omega$   $\stackrel{\sim}{=} 0 \Omega$ . With  $v_n = 0$ , Eq. (1) reduces to  $v_2 = 500$  (- $v_{050}$ ); simposing -0.75 = 500 (- $v_{050}$ ) gives  $v_{050} = 1.5 \text{ mV}$ .

(b) We now have  $R_p = 10^5 \, \Omega$ , and Eq. (1) becomes  $N_2 = 500 \, (R_p T_p - V_{OSO})$ , or  $0.30 = 500 \, (10^5 T_p - 1.5 \, m)$ , which gives  $T_p = 21 \, \text{mA}$ .

(c)  $R_m = 10^5 \Omega$ ,  $N_2 = 500 (-R_m I_N - V_{OSO})$ ,  $-1.70 = 500 (-10^5 I_N - 1.5 mV)$ ,  $I_N = 19 mA$ ;  $I_{OS} = I_P - I_N = 2 mA$ .

(d)  $v_2 = [-V_{050} - (-10)/a], -0.25 = 500 \times [-1.5 \text{ mV} + 10/a] \Rightarrow a = 104 \text{ V/V}.$ 





(5.15)

5.29 (a) R ED=RIN+VN=RIN+VP

INV

= RIN+VOS+V1.

Summing currents 
$$0V_1$$
:

 $\frac{0-V_1}{2R}$ =Ip+  $\frac{V_1-E_0}{3R}$ 

ED =  $\frac{1}{3}$  [5Vos+R(5IN-6Ip)].

(b) 4R KVL:  $V_N=V_1+V_0s$ ; RCL:

 $\frac{E_0-(V_1+V_0s)}{V_1R}=\frac{V_0s}{5R}+I_N$ 

RCL again:

Eliminating  $V_1$ :  $E_0=2V_0s+R(4I_N-I_p)$ 

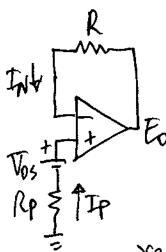
5.30  $V_1$   $V_1+V_0s$   $V_2$ 
 $V_1$   $V_1$   $V_2$   $V_3$ 
 $V_4$   $V_5$ 
 $V_5$ 

RCL  $V_1$   $V_2$ 
 $V_1$   $V_2$ 
 $V_3$ 
 $V_4$   $V_5$ 
 $V_5$ 
 $V_7$ 
 $V_8$ 
 $V_$ 

 $KCLQV_2: \frac{V_1 + V_{05} - V_2}{3R} = \frac{V_2 - E_0}{36R} + \frac{V_2}{12R}$ 

Eliminating Tr and Tr gives Ep=54 Tos +4R (24IN-5IP).

5.31 (a) With Rp=0, E0 = RIN FVN



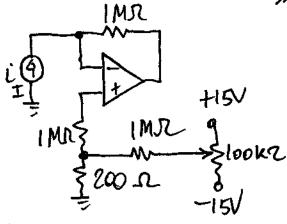
= RTB+VOS

(b) With Rp=R, Eo=Vos-RIOS

€) Eo (max) = 10<sup>-3</sup>+10<sup>6</sup>×10<sup>-9</sup> =2mV. To mill Eo,

return Rp to a variorble voltage

-3mV ≤ tx = +3mV.



5.32 R V R1

IN V R2

Vos T P

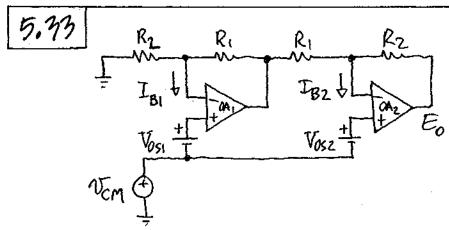
RP T IP

Superposition and kCL:  $V_1 = V_{0S} + RI_N - R_pI_p$   $(E_0 - V_1)/R_2 = I_N + V_1/R_1$ . Eliminating  $V_1$  gives

 $E_0 = \left(1 + \frac{Rz}{R_i}\right) \left[V_{0S} - R_P I_P + \left(R + R_i || \Pi_z\right) I_N\right].$ 

(5.17)

To minimize input-bras surrent errors, use a FET-input of emp, and install a dummy resistance  $R_p = R + R_1//R_2 = 1 \text{ M.IZ}$ , after which  $E_0 = (1+R_2/R_1)[V_{0S} - (R+R_1//R_2)I_{0S}] = 101[V_{0S} - 10^6 F_{0S}]$ . To mult  $E_0$ , return  $R_p$  to a variable voltag  $V_x$  within the range  $-V_2 \leq V_x \leq V_z$ , where  $V_z \neq V_{0S}(mex) + 10^6 I_{0S}(mex)$ .



Since the OP-227 uses input bias-current camallation, there is no point using dummy senistances at the noninverting inputs. The superposition principle gives, for  $V_{CM} = 0$ ,  $E_0 = (H \frac{R^2}{R_1})(\nabla_{052} - \nabla_{051}) - \frac{R^2}{R_1}R_1 I_{B1} + R_2 I_{B2}$ 

$$E_{O(max)} = 100 \left[ 2V_{OS(max)} + 2(R_1||R_2) I_{B(max)} \right]$$
  
= 200  $\left[ V_{OS(max)} + (R_1||R_2) I_{B(max)} \right]$ .

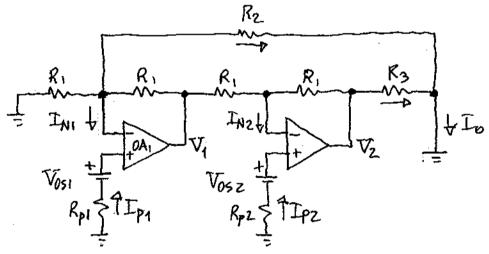
Specify R<sub>1</sub> and R<sub>2</sub> So that  $(R_1||R_2)I_{B(max)} \ll V_{OS(max)}$ , or  $R_1||R_2 = R_1||(99R_1) \cong R_1 \ll (80 \mu V)/(40 mA) = 2 kR$ . For instance, use  $R_1 = 200 \Omega$ ,  $R_2 = 40 mA$ 

(6.18)

19.8 k.l. Then, with  $V_{CM} = 0 \text{ V}$ ,  $E_{O(max)} = 17.6 \text{ mV}$ .

Rising  $V_{CM}$  to 10 V changes  $V_{OS1}$  and  $V_{OS2}$  by as much as  $(10 \text{ V})/10^{114/20} \cong 20 \text{ uV/V}$ . Moreover,  $V_{OS1}$  experiences an additional change of  $V_{OI}|a_{I(min)} = 10/10^6 = 1 \text{ uV}$ . We thus have, for  $V_{CM} = 10 \text{ V}$ ,  $E_{O(max)} \cong 17.6 \text{ mV} + 100(21 + 20) \text{ uV} = 21.7 \text{ mV}$ .

5.34 The presence of the brias currents and offset voltages does not affect the resistances of the aicuit, so we expect A and Ro to remain the same. The only effect is to produce an output ever To.

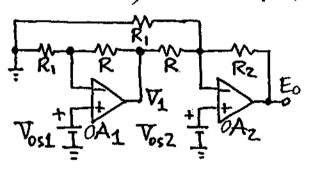


$$\begin{split} & \text{I}_0 = V_{N1}/R_2 + V_Z/R_3. \text{ In a well-designed aircuit} \\ & \text{we usually have } R_3 \ll R_Z \text{ for efficiency, so we} \\ & \text{need to minimize } V_Z. \text{ Superposition:} \\ & V_2 = (1 + R_1/R_1) (V_0 s_2 - R_{PZ} I_{PZ}) + R_1 I_{NZ} - (R_1/R_1) V_1. \\ & = 2 \left[ V_0 s_2 - R_{PZ} I_{PZ} + (R_1/Z) I_{NZ} \right] - V_1. \\ & \Rightarrow \text{Vse } R_{PZ} = R_1/2 \text{ to minimize effect of } I_{BZ}. \\ & V_1 = \left[ 1 + R_1/(R_1||R_Z) \right] (V_0 s_1 - R_{P1} I_{P1}) + R_1 I_{N1} \end{split}$$

=  $(2+R_1/R_2) \{V_{0S1}-R_{P1}I_{P1}+[(R_1/2)||R_2]I_{N1}\}$   $\Rightarrow$  Use  $R_{P1}=(R_1/2)||R_2$  to minimize effect of  $I_{B1}$ . Worst-case output error is then  $I_0(mex) = \frac{V_{0S1}+R_{P1}I_{B1}}{R_2} + \frac{1}{R_3} \{2V_{0S2} + \frac{R_1}{2}I_{0S2} + \frac{R_1}{R_2}I_{0S2} + \frac{R_1}{R_2}I_{0S1}\}.$ 

To mill Io, return Rpz to a variable voltage  $\nabla x$ ,  $\forall x \leq \nabla x \leq \nabla x$ ,  $\nabla x \neq 2 \overline{\nabla}_{052} + (R_1/2) \overline{I}_{052} + 3(\overline{\nabla}_{051} + Rp_1 \overline{I}_{051})$ , where the overbar indicates mox value.

[5.35] (a)  $V_1 = (1+R/R_1)V_{ost}$ . Superposition:



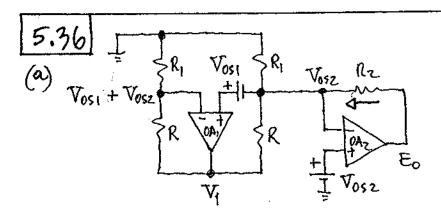
$$E_o = -\frac{Rz}{R}V_1 + \left(1 + \frac{P_2}{R_1/R}\right)V_{052}$$

Eliminating V1

and manipulating,

 $E_0 = V_{052} + \frac{R_2}{R_1/\!\!/R} (V_{052} - V_{051}).$ 

(b) Lift OAzs moninverting input and return it to a variable voltage Vx, -V2 ≤ Vx ≤ Vz, Vz = Eo(mex)/[1+Rz/(R:11R)]. (5.20)



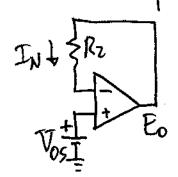
KCL:  $(E_0-V_{052})/R_2=V_{052}/R_1+(V_{052}-V_1)/R$ , where  $V_4=(1+R/R_1)(V_{051}+V_{052})$ . Eliminating  $V_4$ ,  $E_0=V_{052}-[R_1/(R_1/|R)]V_{051}$ .

(b) Lift  $0A_2$ 's noninverting input and return it to a variable voltage  $\nabla_x$ ,  $-\nabla_2 \leq V_x$   $\leq \nabla_2$ ,  $\nabla_2 \approx V_{0SZ(max)} + [R_Z/(R_1+R)]V_{0SI(max)}$ .

[5.37] Fig. 2.1:  $E_0 = V_{OS} - RIos$ .  $E_0(max) = 10^{-3} + 10^6 \times 2 \times 10^{-9} = 3 \text{ mV}$ . Fig. 2.2: using the superposition principle,  $E_0 = Req I_N + (1+R_2/R_1)(V_{OS} - Rp I_p)$ , where  $Req = (1+20/100 + 20/2.26)100 = 1 M_{I}$ ,  $1+R_2/R_1 = 9.8$ ,  $(1+R_2/R_1)R_p = 1 M_{I}$ . Thus,  $E_0 = (1+R_2/R_1)V_{OS} - Req I_{OS}$ , and  $E_0(max) = 9.8 \times 10^{-3} + 10^6 \times 2 \times 10^{-9} = 9.8 + 2 = 11.8 \text{ mV}$ . While the contribution from  $I_{OS}$  is the same, that from  $V_{OS}$  is much larger in the second circuit due to the fact that the moise gain is unity in the first evicuit, but  $1+R_2/R_1$  in the second.

(5.21)

5.38 De equivalent is as shown:



Po=Vos+R2IN =Vos+R2IB = 10<sup>3</sup>+316×10<sup>3</sup> × 50×10<sup>9</sup> =16.8 mV. Tommimize the output error,

return the moninverting input to ground ria a dummy resistance Rp = Rz = 316 M. Then, Eo = Vos - Rz Tos, and  $IEo I max = 10^{-3} + 316 \times 10^{3} \times 5 \times 10^{-9} = 2.58 \text{ mV}$ . Tomell this residual error, return Rp to a variable voltage  $V_x$ ,  $-3mV \leq V_x \leq 3mV$ .

Ne either scale Rx and RB to achieve RX/1RB = RI+RZ Nohile retaining the same Tratio in order to leave Qunchanged, or we leave them as they are but mosert a dummy resistance Rp = R1+R2-RA//RB = 25.2 kg, as shown. In either case we have:

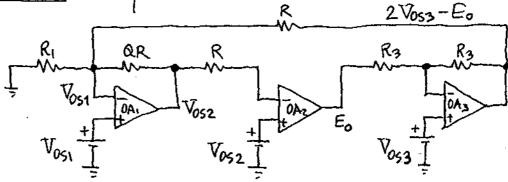
Eo = (I+ (B)) [Vos-(RITRZ) Ios], | Eolmex = 2.8 (10-3+31.6×103x 5×10-9)=3.24 mV. To mull it, return RA to RA \ \ \frac{9.76 \text{kr}}{240.92} \ \ -15V a variable voltage Vx, -3.5mV ≤ Vx =3.5mV as Shown

5,40 Both circuits have a dc equir-To minimize the error, insert a dummy resistor Ry = Rx- (RA//RB). Then, the outpout even in Eo=(I+RB/RA)(Vos-RxIos). Example 3.13: Px=Rz=22,5kR, Rg= 22.5-(10/128.7)=15kl. | Eo/max=3.86x  $(1+22.5\times10^{3}\times5\times10^{7})=4.3\,\text{mV}$ Example 3.14: Rx = 2R = 53.1 kr.; Ry = 53.1 - 0.870 = 52 kr. | Eo | mex = (47/12) x (10-3+53.1×103×5×159)=4.94 mV.

\$ 9.76 hr \$ To mull the error split Ra and use external mulling as shown.

5.23)



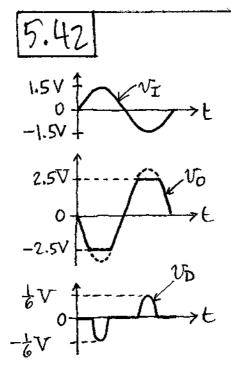


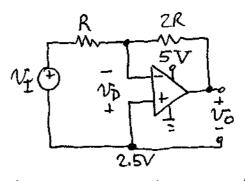
KCL: 
$$\frac{V_{052}-V_{051}}{QR} + \frac{0-V_{051}}{R_1} + \frac{(2V_{053}-E_0)-V_{051}}{R} = 0$$

$$\Rightarrow E_0 = 2V_{053} - \left(1 + \frac{1}{Q} + \frac{R}{R_1}\right)V_{051} + \frac{V_{052}}{Q}$$

$$E_0(max) = \left[2 + \left(1 + \frac{1}{40} + \frac{20}{78.7}\right) + \frac{1}{40}\right]5 \times 10^{-3} = 16.3 \text{ mV}.$$

To mull Eo, return OA's moninverting input to an adjustable voltage Vx such that





\*E (a) As No tries to swing to  $\pm 3V$ , it clips at  $\pm 2.5V$ ; also,  $V_D$  peaks at  $\pm (\frac{2}{3}1.5 - \frac{1}{3}2.5) = \pm \frac{1}{6}V$ . (b)  $V_I = 1.25 \sin \omega t$  V. [5.43] (a)  $i_0 = 10/2 = 5 \text{ mA}$ ;  $v_{R_6} = 0.027 \times 5 = 0.135 \text{ V}$ ;  $Q_{15} = 0\text{ff}$ ;  $i_{C15} = 0$ ;  $i_{C14} = i_0 = 5 \text{ mA}$ ;  $v_{R2} = 10 + 0.135 + 0.7 = 8.735 \text{ V}$ .

(b)  $10/0.2 = 50 \text{ mA} > 0.7/27 \approx 26 \text{ mA} \Rightarrow$   $i_0 \approx 26 \text{ mA}$ ;  $v_0 \approx 0.2 \times 26 = 5.2 \text{ V}$ ;  $i_{c14} \approx i_0 \approx$  26 mA;  $i_{c15} = 0.18 - 26/250 = 76 \text{ mA}$ ;  $P_{Q14} \approx$ (15-5.2)26 = 255 mW;  $v_{B22}$  close to  $v_{cc}$ .